TEXAS INSTRUMENTS
Data sheet acquired from Harris Semiconductor
SCHS082

CD4532B Types

CMOS 8-Bit Priority Encoder

High-Voltage Types (20-Volt Rating)

■ CD4532B consists of combinational logic that encodes the highest priority input (D7-D0) to a 3-bit binary code. The eight inputs, D7 through D0, each have an assigned priority; D7 is the highest priority and D0 is the lowest. The priority encoder is inhibited when the chip-enable input E_I is low. When E_I is high, the binary representation of the highest-priority input appears on output lines Q2-Q0, and the group select line GS is high to indicate that priority inputs are present. The enable-out (E_O) is high when no priority inputs are present. If any one input is high, E_O is low and all cascaded lower-order stages are disabled.

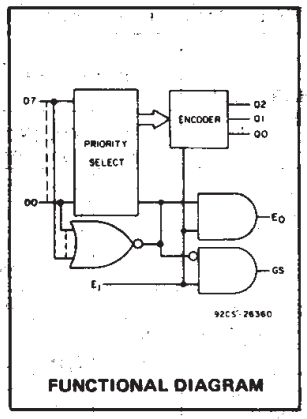
The CD4532B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- Converts from 1 of 8 to binary
- Provides cascading feature to handle any number of inputs
- Group select indicates one or more priority inputs
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range):
  - 0.5 V at V_{DD} = 5 V
  - 1.5 V at V_{DD} = 10 V
  - 1.5 V at V_{DD} = 15 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Priority encoder
- Binary or BCD encoder (keyboard encoding)
- Floating point arithmetic



FUNCTIONAL DIAGRAM

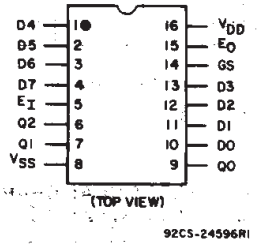
RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

Characteristic	Min.	Max.	Units
Supply Voltage Range (for T_A = Full Package Temp. Range)	3	18	V

MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY-VOLTAGE RANGE, (V_{DD})
(Voltages referenced to V_{SS} Terminal) ..... -0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to V_{DD} +0.5V
DC INPUT CURRENT, ANY ONE INPUT ..... ±10mA
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = -55°C to +100°C 500mW
For T_A = +100°C to +125°C ..... Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T_A) ..... -55°C to +125°C
STORAGE TEMPERATURE RANGE (T_{stg}) ..... -65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max ..... +265°C



TERMINAL ASSIGNMENT

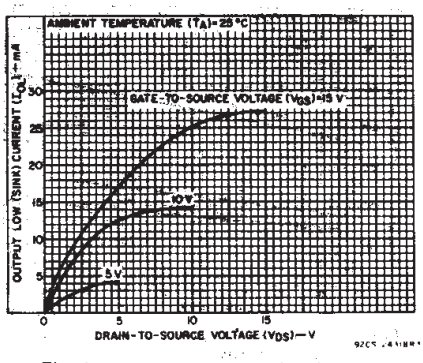


Fig. 1 — Typical output low (sink) current characteristics.

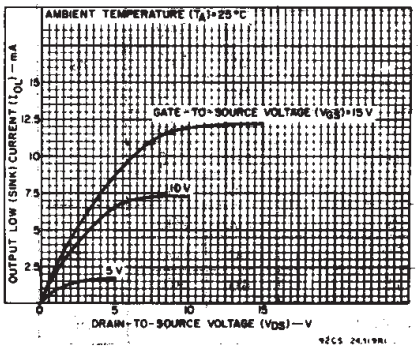


Fig. 2 — Minimum output low (sink) current characteristics.

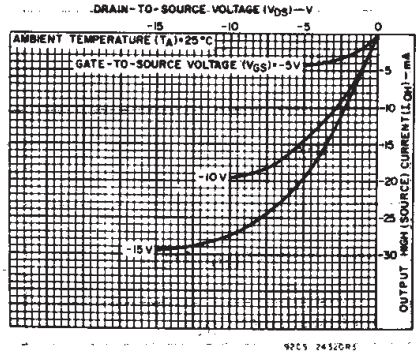


Fig. 3 — Typical output high (source) current characteristics.

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
								+25			
	V_O (V)	V_{IN} (V)	V_{DD} (V)	−55	−40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I_{DD} Max.	–	0,5	5	5	5	150	150	–	0.04	5	μA
	–	0,10	10	10	10	300	300	–	0.04	10	
	–	0,15	15	20	20	600	600	–	0.04	20	
	–	0,20	20	100	100	3000	3000	–	0.08	100	
Output Low (Sink) Current I_{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	–	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	–	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	–	
Output High (Source) Current, I_{OH} Min.	4.6	0,5	5	−0.64	−0.61	−0.42	−0.36	−0.51	−1	–	
	2.5	0,5	5	−2	−1.8	−1.3	−1.15	−1.6	−3.2	–	
	9.5	0,10	10	−1.6	−1.5	−1.1	−0.9	−1.3	−2.6	–	
	13.5	0,15	15	−4.2	−4	−2.8	−2.4	−3.4	−6.8	–	
Output Voltage: Low-Level, V_{OL} Max.	–	0,5	5	0.05				–	0	0.05	V
	–	0,10	10	0.05				–	0	0.05	
	–	0,15	15	0.05				–	0	0.05	
Output Voltage: High-Level, V_{OH} Min.	–	0,5	5	4.95				4.95	5	–	
	–	0,10	10	9.95				9.95	10	–	
	–	0,15	15	14.95				14.95	15	–	
Input Low Voltage, V_{IL} Max.*	0.5, 4.5	–	5	1				—	—	1.5	V
	1, 9	–	10	2.5				–	—	3	
	1.5,13.5	–	15	3				–	—	4	
Input High Voltage, V_{IH} Min.*	0.5, 4.5	–	5	4				3.5	—	—	
	1, 9	–	10	7.5				7	—	—	
	1.5,13.5	–	15	12				11	—	—	
Input Current I_{IN} Max.		0,18	18	±0.1	±0.1	±1	±1	–	$±10^{-5}$	±0.1	μA

*One input is tested at a time; other inputs should be at V_{DD} or V_{SS}. For testing all inputs at V_{IL} and V_{IH} levels, use 20%/80% V_{DD}.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A=25°C; C_L=50 pF, Input t_r,t_f= 20 ns, R_L=200 KΩ

CHARACTERISTIC	TEST CONDITIONS V_{DD} VOLTS	LIMITS		UNITS
		TYP.	MAX.	
Propagation Delay Time t_{PHL}, t_{PLH}	5	110	220	ns
E_I to E_O, E_I to GS	10	55	110	
	15	45	85	
E_I to Qm, Dn to GS	5	170	340	
	10	85	170	
	15	65	125	
Dn to Q_M	5	220	440	
	10	110	220	
	15	85	160	
Transition Time t_{THL}, t_{TLH}	5	100	200	ns
	10	50	100	
	15	40	80	
Input Capacitance C_{IN}	Any Input	5	7.5	pF

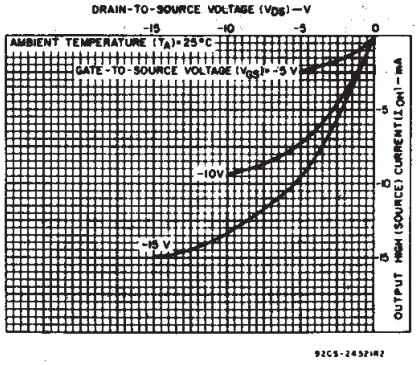


Fig. 4 — Minimum output high (source) current characteristics.

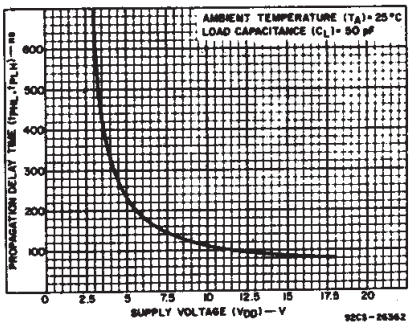


Fig. 5 — Typical propagation delay (Dn to Qm) vs. supply voltage.

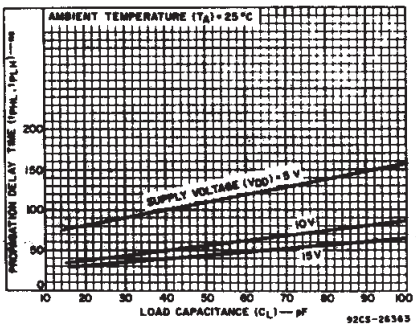


Fig. 6 — Typical propagation delay (E_I to GS, E_I to E_O) vs. load capacitance.

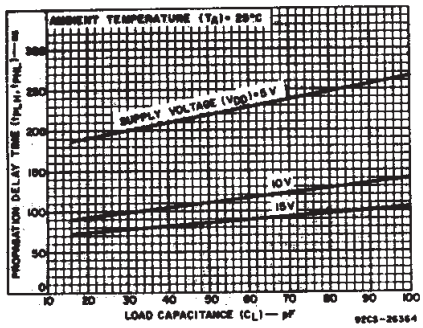


Fig. 7 — Typical propagation delay (Dn to Qm) vs. load capacitance.

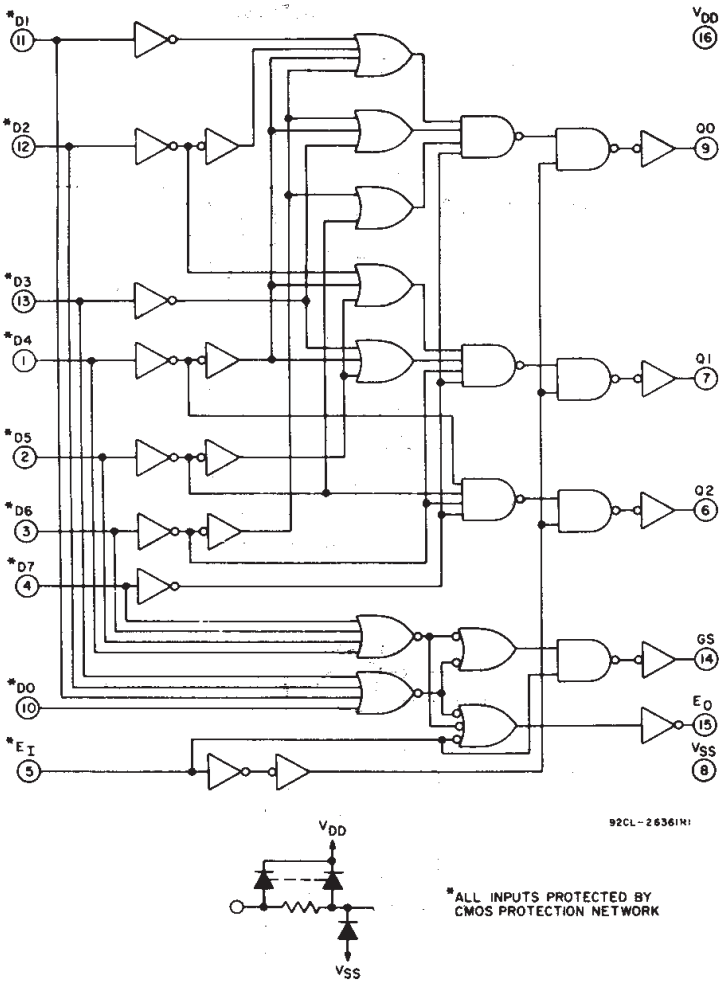


Fig. 8 – CD4532 logic diagram.

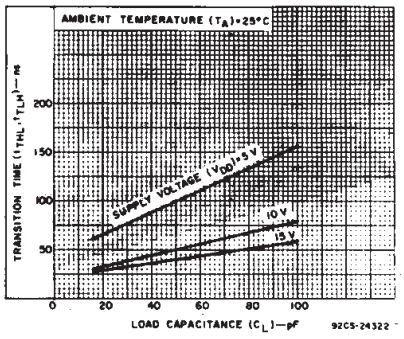


Fig.9 – Typical transition time vs. load capacitance.

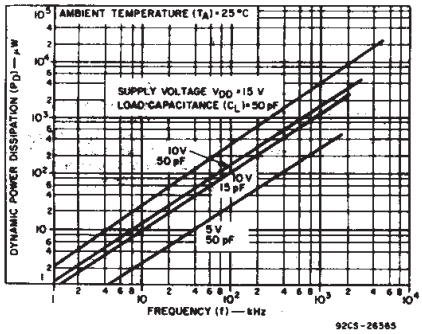


Fig.10 – Typical dynamic power dissipation vs. frequency.

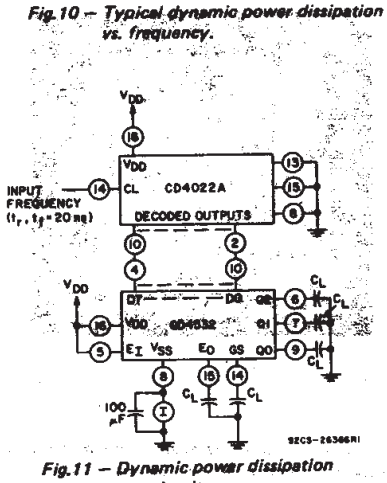


Fig.11 – Dynamic power dissipation test circuit.

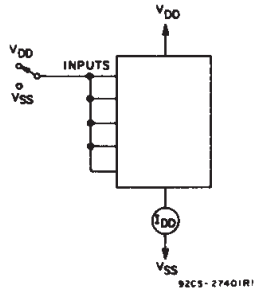


Fig.12 – Quiescent device current test circuit.

TRUTH TABLE

Input									Output				
E_I	D7	D6	D5	D4	D3	D2	D1	D0	GS	Q2	Q1	Q0	E_O
0	X	X	X	X	X	X	X	X	0	0	0	0	0
1	0	0	0	0	0	0	0	0	0	0	0	0	1
1	1	X	X	X	X	X	X	X	1	1	1	1	0
1	0	1	X	X	X	X	X	X	1	1	1	0	0
1	0	0	1	X	X	X	X	X	1	1	0	1	0
1	0	0	0	1	X	X	X	X	1	1	0	0	0
1	0	0	0	0	1	X	X	X	1	0	1	1	0
1	0	0	0	0	0	1	X	X	1	0	1	0	0
1	0	0	0	0	0	0	1	X	1	0	0	1	0
1	0	0	0	0	0	0	0	1	1	0	0	0	0

X = Don't Care Logic 1 ≡ High Logic 0 ≡ Low

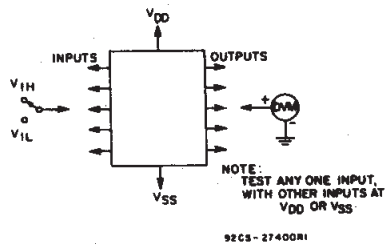


Fig. 13 – Input voltage test circuit.

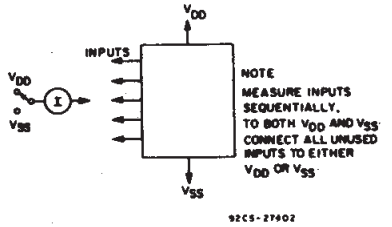
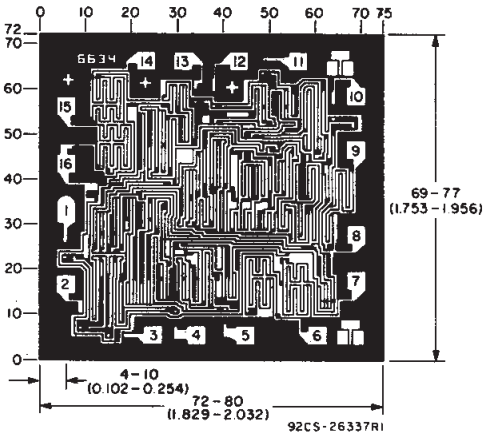


Fig. 14 – Input current test circuit.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Dimensions and pad layout for CD4532BH.

APPLICATIONS

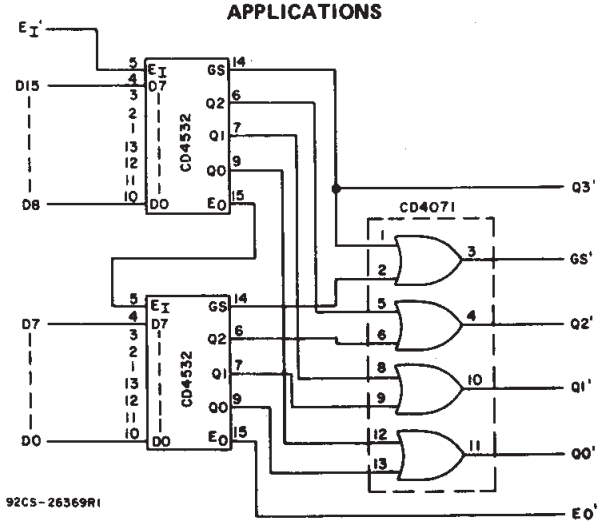
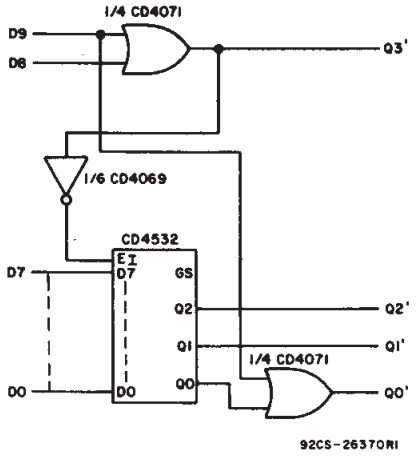


Fig. 15 – 16-level priority encoder.



TRUTH TABLE

Input										Output				
D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	GS	Q3'	Q2'	Q1'	Q0'
1	X	X	X	X	X	X	X	X	X	0	1	0	0	1
0	1	X	X	X	X	X	X	X	X	0	1	0	0	0
0	0	1	X	X	X	X	X	X	X	1	0	1	1	1
0	0	0	1	X	X	X	X	X	X	1	0	1	1	0
0	0	0	0	1	X	X	X	X	X	1	0	1	0	1
0	0	0	0	0	1	X	X	X	X	1	0	1	0	0
0	0	0	0	0	0	1	X	X	X	1	0	0	1	1
0	0	0	0	0	0	0	1	X	X	1	0	0	1	0
0	0	0	0	0	0	0	0	1	X	1	0	0	0	1
0	0	0	0	0	0	0	0	0	1	1	0	0	0	0

X = Don't Care Logic 1 ≡ High Logic 0 ≡ Low

Fig. 16 – 0-to-9 keyboard encoder.

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